

MINISTRY OF SUPPLY (S.R.D.E.)

Specification MOS/CV1947/Issue 2 Dated:- 4.5.49. To be read in conjunction with K1001.	<u>SECURITY</u> <u>Specification</u> <u>Valve</u> Restricted Unclassified
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<u>TYPE OF VALVE:-</u> Beam Power Amplifier			<u>MARKING</u> See K1001/4.		
<u>CATHODE:-</u> Indirectly heated					
<u>ENVELOPE:-</u> Glass-ummatalised			<u>PACKAGING</u> See K1005.		
<u>PROTOTYPE:-</u> 6L6G.					
<u>RATING</u>			<u>BASE</u> See K1001/A1/D2 M Dimension IO (V) applies		
			Note		
Heater voltage (V) 6.3			Pin	Electrode	
Heater current (A) 0.9				No connection	
Max. anode voltage (V) 400				Heater	
Max. screen voltage (V) 300				Anode	
Max. anode dissipation (W) 21				Screen Grid	
Max. screen dissipation (W) 2.75				Control Grid	
Mutual conductance (mA/V) 6.0				Pin omitted	
				Heater	
			Cathode and beam-forming plates		
<u>CAPACITANCES (pF)</u>			<u>DIMENSIONS</u> See K1001/A1/D1.		
Cag 0.9					
Cae 9.5					
Cge 11.5					
<u>NOTE</u>			Dimensions Min. Max.		
A. Measured at $V_a = V_{g2} = 250V$.			A mm. - 136		
$V_{g1} = -14.0 V$.			B mm. - 53		

TESTS

To be performed in addition to those applicable in K1001

	Test Conditions				Test	Limits		No. Tested
						Min.	Max.	
	Vh	Va	Vg2	Vg1				
a	6.3	-	-	-	Ih (A)	0.84	0.96	100% Or S
b	6.3	250	250	-14	Ia (mA)	58	86	100%
c	6.3	250	250	-14	Ig2 (mA)	-	8.0	100% or S
d	6.3	250	250	-14	gm (mA/V)	5.2	6.8	100%
e	6.3	250	250	-14	Rev. Ig1 (μA)	-	3.0	100%
f	6.3	50	50	50	Emission (mA)	275	-	100%